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April 1<sup>st</sup>, 20<mark>10</mark> Renesas Electronics Corporation

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# MOS INTEGRATED CIRCUIT $\mu PD43257B$

# 256K-BIT CMOS STATIC RAM 32K-WORD BY 8-BIT

#### **Description**

The  $\mu$ PD43257B is a high speed, low power, and 262,144 bits (32,768 words by 8 bits) CMOS static RAM. Battery backup is available. And the  $\mu$ PD43257B has two chip enable pins (/CE1, CE2) to extend the capacity. The  $\mu$ PD43257B is packed in 28-pin PLASTIC SOP.

#### **Features**

32,768 words by 8 bits organization
Fast access time: 70, 85 ns (MAX.)
Low Vcc data retention: 2.0 V (MIN.)
Two Chip Enable inputs: /CE1, CE2

Part number	Access time	Operating supply	Operating ambient	Supply current			
	ns (MAX.)	voltage	voltage temperature		At standby	At data retention	
		V	°C	mA (MAX.)	μ <b>Α</b> (ΜΑΧ.)	μΑ (MAX.) Note	
μPD43257B-xxL	70, 85	4.5 to 5.5	0 to 70	45	50	3	
μPD43257B-xxLL				45	15	2	

Note TA  $\leq$  40 °C, Vcc = 3.0 V

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# **Ordering Information**

Part number	Package	Access time	Supply curre	Supply current $\mu$ A (MAX.)	
		ns (MAX.)	At standby	At data retention Note	
μPD43257BGU-70L	28-pin PLASTIC SOP	70	50	3	L version
μPD43257BGU-85L	(11.43 mm (450))	85			
μPD43257BGU-70LL		70	15	2	LL version
μPD43257BGU-85LL		85			
μPD43257BGU-70L-A	28-pin PLASTIC SOP	70	50	3	L version
μPD43257BGU-85L-A	(11.43 mm (450))	85			
μPD43257BGU-70LL-A		70	15	2	LL version
μPD43257BGU-85LL-A		85			

Note Ta  $\leq$  40 °C, Vcc = 3.0 V

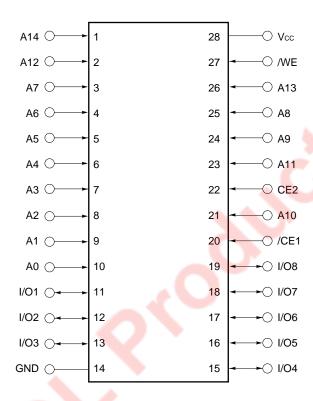
**Remark** Products with -A at the end of the part number are lead-free products.



# Pin Configurations (Marking Side)

/xxx indicates active low signal.

28-pin PLASTIC SOP (11.43 mm (450))
[ μPD43257BGU-xxL ]
[ μPD43257BGU-xxLL ]
[ μPD43257BGU-xxL-A ]
[ μPD43257BGU-xxLL-A ]



A0 - A14 : Address inputs

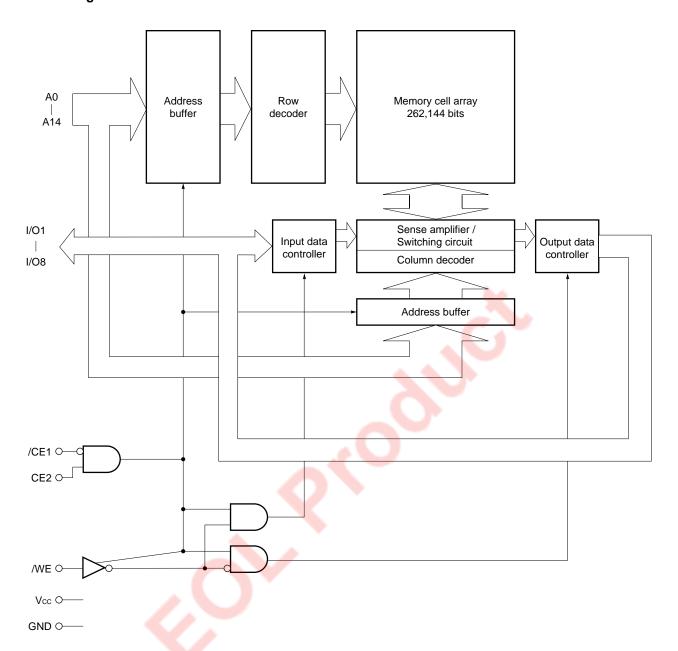
I/O1 - I/O8 : Data inputs / outputs

/CE1 : Chip Enable 1
CE2 : Chip Enable 2
/WE : Write Enable
Vcc : Power supply

GND : Ground

Remark Refer to Package Drawings for the 1-pin marking.

# **Block Diagram**



# **Truth Table**

/CE1	CE2	/WE	Mode	I/O	Supply current
Н	×	×	Not selected	High impedance	IsB
×	L	×			
L	Н	Н	Read	<b>D</b> оит	ICCA
L	Н	L	Write	Din	

 $\textbf{Remark} \ \times \ : \ V \text{IH or } V \text{IL}$ 



#### **Electrical Specifications**

#### **Absolute Maximum Ratings**

Parameter	Symbol	Condition	Rating	Unit
Supply voltage	Vcc		-0.5 <sup>Note</sup> to +7.0	٧
Input / Output voltage	VT		-0.5 Note to Vcc + 0.5	V
Operating ambient temperature	TA		0 to 70	°C
Storage temperature	Tstg		-55 to +125	°C

Note −3.0 V (MIN.) (Pulse width : 50 ns)

Caution Exposing the device to stress above those listed in Absolute Maximum Rating could cause permanent damage. The device is not meant to be operated under conditions outside the limits described in the operational section of this specification. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

#### **Recommended Operating Conditions**

Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
Supply voltage	Vcc		4.5	5.0	5.5	V
High level input voltage	VIH		2.2		Vcc+0.5	٧
Low level input voltage	VIL		-0.3 Note		+0.8	٧
Operating ambient temperature	TA		0		70	°C

Note -3.0 V (MIN.) (Pulse width: 50 ns)

#### Capacitance (T<sub>A</sub> = 25 °C, f = 1 MHz)

Parameter	Symbol	Test conditions	MIN.	TYP.	MAX.	Unit
Input capacitance	CIN	V <sub>IN</sub> = 0 V			5	pF
Input / Output capacitance	Ci/o	V <sub>I/O</sub> = 0 V			8	pF

Remarks 1. Vin : Input voltage

Vi/o: Input / Output voltage

2. These parameters are periodically sampled and not 100% tested.



# DC Characteristics (Recommended Operating Conditions Unless Otherwise Noted)

Parameter	Symbol	Test condition		μPD	μPD43257B-xxL			μPD43257B-xxLL		
				MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
Input leakage current	lu	V <sub>IN</sub> = 0 V to V <sub>CC</sub>		-1.0		+1.0	-1.0		+1.0	μΑ
I/O leakage current	lιο	$V_{I/O} = 0$ V to $V_{CC}$ , $/CE1 = V_{IH}$ or $CE2 = V_{IL}$ or $/WE = V_{IL}$	,			+1.0	-1.0		+1.0	μΑ
Operating	ICCA1	/CE1 = V <sub>IL</sub> , CE2 = V <sub>IH</sub> ,	μPD43257B-70			45			45	mA
supply current		Minimum cycle time, I <sub>I/O</sub> = 0 mA	μPD43257B-85			45			45	
	ICCA2	/CE1 = V <sub>IL</sub> , CE2 = V <sub>IH</sub> , I <sub>I/O</sub> = 0 mA				10			10	
	Іссаз	/CE1 $\leq$ 0.2 V, CE2 $\geq$ Vcc $-$ 0.2 V, Cy I <sub>I/O</sub> = 0 mA, V <sub>IL</sub> $\leq$ 0.2 V, V <sub>IH</sub> $\geq$ Vcc $-$ 0	•			10			10	
Standby	Isa	/CE1 = V <sub>IH</sub> or CE2 = V <sub>IL</sub> ,				3			3	mA
supply current	I <sub>SB1</sub>	/CE1 ≥ Vcc - 0.2 V, CE2 ≥ Vcc - 0.2	2 V		1.0	50		0.5	15	μΑ
	I <sub>SB2</sub>	CE2 ≤ 0.2 V			1.0	50		0.5	15	
High level	V <sub>OH1</sub>	loн = -1.0 mA		2.4		1	2.4			V
output voltage	V <sub>OH2</sub>	I <sub>OH</sub> = -0.1 mA		Vcc–0.5			Vcc-0.5			
Low level output voltage	Vol	IoL = 2.1 mA				0.4			0.4	V

Remarks 1. VIN: Input voltage

VI/o : Input / Output voltage

2. These DC characteristics are in common regardless of package types and access time.

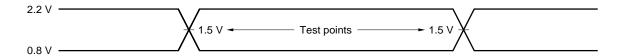


#### AC Characteristics (Recommended Operating Conditions Unless Otherwise Noted)

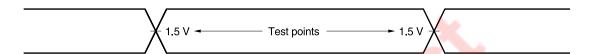
#### **AC Test Conditions**

#### [ $\mu$ PD43257B-70L, $\mu$ PD43257B-85L, $\mu$ PD43257B-70LL, $\mu$ PD43257B-85LL ]

#### Input Waveform (Rise and Fall Time ≤ 5 ns)

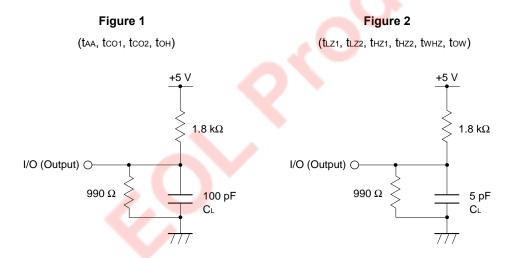


#### **Output Waveform**



# **Output Load**

AC characteristics with notes should be measured with the output load shown in Figure 1 and Figure 2.



 $\textbf{Remark} \;\; \textbf{C} \textbf{$\scriptscriptstyle{L}$ includes capacitance of the probe and jig, and stray capacitance.}$ 

# **Read Cycle**

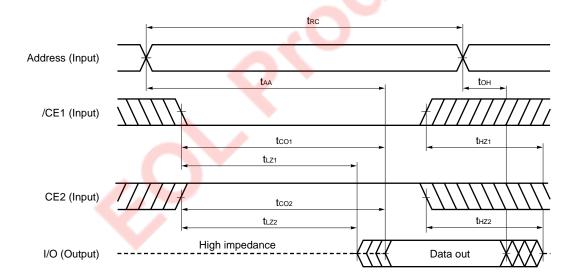
Parameter	Symbol	<i>μ</i> PD432	257B-70	μPD43257B-85		Unit	Condition
		MIN.	MAX.	MIN.	MAX.		
Read cycle time	<b>t</b> rc	70		85		ns	
Address access time	<b>t</b> AA		70		85	ns	Note 1
/CE1 access time	<b>t</b> co1		70		85	ns	
CE2 access time	<b>t</b> co2		70		85	ns	
Output hold from address change	tон	10		10		ns	
/CE1 to output in low impedance	t <sub>LZ1</sub>	10		10		ns	Note 2
CE2 to output in low impedance	t <sub>LZ2</sub>	10		10		ns	
/CE1 to output in high impedance	<b>t</b> HZ1		30		30	ns	
CE2 to output in high impedance	t <sub>HZ2</sub>		30		30	ns	

Notes 1. See the output load shown in Figure 1.

2. See the output load shown in Figure 2.

**Remark** These AC characteristics are in common regardless of package types and L, LL versions.

# **Read Cycle Timing Chart**



**Remark** In read cycle, /WE should be fixed to high level.



# Write Cycle

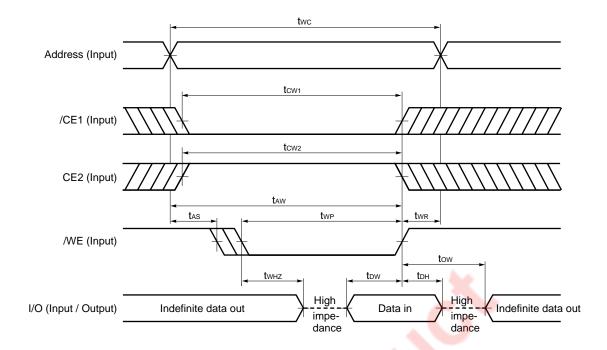
Parameter	Symbol	<i>μ</i> PD432	257B-70	μPD43257B-85		Unit	Condition
		MIN.	MAX.	MIN.	MAX.		
Write cycle time	<b>t</b> wc	70		85		ns	
/CE1 to end of write	tcw1	50		70		ns	
CE2 to end of write	tcw2	50		70		ns	
Address valid to end of write	taw	50		70		ns	
Address setup time	<b>t</b> as	0		0		ns	
Write pulse width	twp	55		65		ns	
Write recovery time	<b>t</b> wr	0		0		ns	
Data valid to end of write	<b>t</b> ow	30		35		ns	
Data hold time	<b>t</b> DH	0		0		ns	
/WE to output in high impedance	<b>t</b> wnz		30		30	ns	Note
Output active from end of write	tow	10		10	<b>S</b>	ns	

Note See the output load shown in Figure 2.

Remark These AC characteristics are in common regardless of package types and L, LL versions.



# Write Cycle Timing Chart 1 (/WE Controlled)



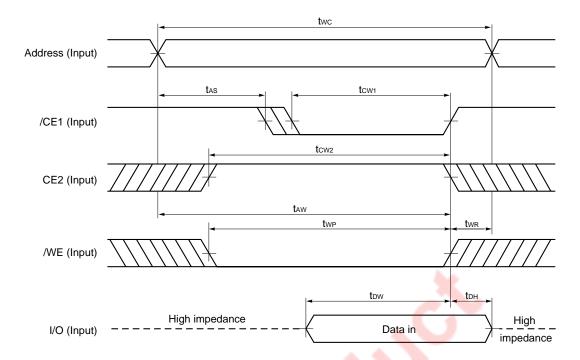
Cautions 1. During address transition, at least one of pins /CE1, CE2, /WE should be inactivated.

2. When I/O pins are in the output state, therefore the input signals must not be applied to the output.

Remarks 1. Write operation is done during the overlap time of a low level /CE1, /WE and a high level CE2.

- 2. If /CE1 changes to low level at the same time or after the change of /WE to low level, or if CE2 changes to high level at the same time or after the change of /WE to low level, the I/O pins will remain high impedance state.
- 3. When /WE is at low level, the I/O pins are always high impedance. When /WE is at high level, read operation is executed. Therefore /OE should be at high level to make the I/O pins high impedance.

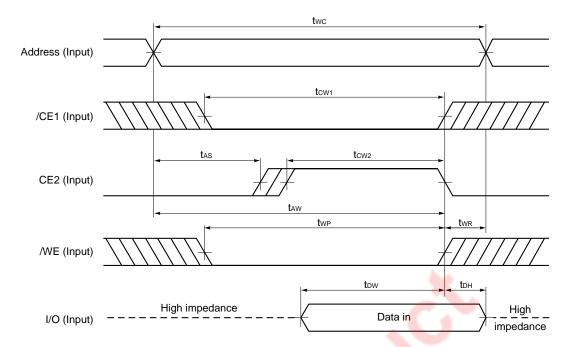
# Write Cycle Timing Chart 2 (/CE1 Controlled)



- Cautions 1. During address transition, at least one of pins /CE1, CE2, /WE should be inactivated.
  - 2. When I/O pins are in the output state, therefore the input signals must not be applied to the output.

**Remark** Write operation is done during the overlap time of a low level /CE1, /WE and a high level CE2.

# Write Cycle Timing Chart 3 (CE2 Controlled)



- Cautions 1. During address transition, at least one of pins /CE1, CE2, /WE should be inactivated.
  - 2. When I/O pins are in the output state, therefore the input signals must not be applied to the output.

**Remark** Write operation is done during the overlap time of a low level /CE1, /WE and a high level CE2.



# Low Vcc Data Retention Characteristics (T<sub>A</sub> = 0 to 70 °C)

Parameter	Symbol	nbol Test Condition		μPD43257B-xxL			μPD43257B-xxLL			
			MIN.	TYP.	MAX.	MIN.	TYP.	MAX.		
Data retention supply voltage	Vccdr1	/CE1 ≥ Vcc - 0.2 V, CE2 ≥ Vcc - 0.2 V	2.0		5.5	2.0		5.5	٧	
	Vccdr2	CE2 ≤ 0.2 V	2.0		5.5	2.0		5.5		
Data retention supply current	ICCDR1	Vcc = 3.0 V, /CE1 ≥ Vcc – 0.2 V, CE2 ≥ Vcc – 0.2 V		0.5	20 Note1		0.5	7 Note2	μА	
	Iccdr2	Vcc = 3.0 V, CE2 ≤ 0.2 V		0.5	20 Note1		0.5	7 Note2		
Chip deselection to data retention mode	tcdr		0			0			ns	
Operation recovery time	<b>t</b> R		5			5			ms	

**Notes 1.**  $3 \mu A (T_A \le 40 \, ^{\circ}C)$ 

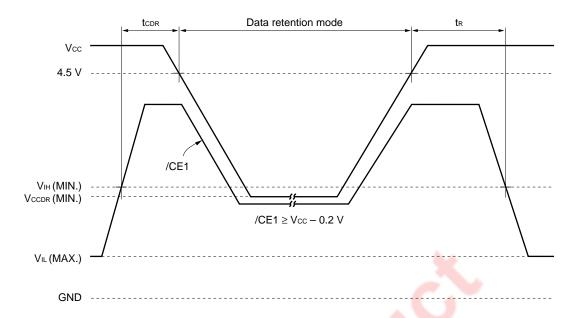
**2.**  $2 \mu A (T_A \le 40 \, ^{\circ}C)$ ,  $1 \mu A (T_A \le 25 \, ^{\circ}C)$ 



Data Sheet M10693EJAV0DS 13

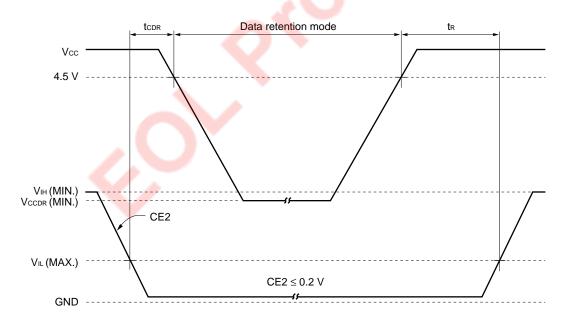
# **Data Retention Timing Chart**

#### (1) /CE1 Controlled



**Remark** On the data retention mode by controlling /CE1, the input level of CE2 must be CE2  $\geq$  Vcc - 0.2 V or CE2  $\leq$  0.2 V. The other pins (Address, I/O, /WE) can be in high impedance state.

#### (2) CE2 Controlled

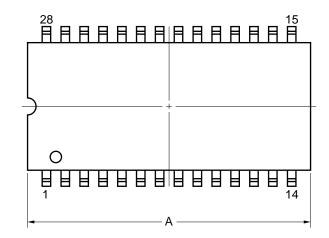


**Remark** On the data retention mode by controlling CE2, the other pins (/CE1, Address, I/O, /WE) can be in high impedance state.



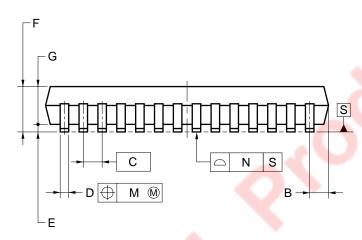
# **Package Drawings**

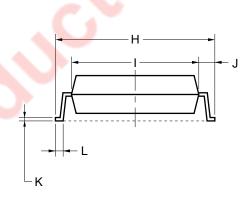
# 28-PIN PLASTIC SOP (11.43 mm (450))



detail of lead end







#### NOTE

Each lead centerline is located within 0.12 mm of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS
А	$18.0^{+0.6}_{-0.05}$
В	1.27 MAX.
С	1.27 (T.P.)
D	$0.42^{+0.08}_{-0.07}$
Е	0.2±0.1
F	2.95 MAX.
G	2.55±0.1
Н	11.8±0.3
	8.4±0.1
J	1.7±0.2
K	0.22±0.05
L	0.7±0.2
М	0.12
N	0.10
Р	3°+7°

P28GU-50-450A-4



#### **Recommended Soldering Conditions**

Please consult with our sales offices for soldering conditions of the  $\mu$ PD43257B.

#### **Types of Surface Mount Device**

μPD43257BGU-xxL : 28-pin PLASTIC SOP (11.43 mm (450)) μPD43257BGU-xxL-A : 28-pin PLASTIC SOP (11.43 mm (450)) μPD43257BGU-xxL-A : 28-pin PLASTIC SOP (11.43 mm (450)) μPD43257BGU-xxLL-A : 28-pin PLASTIC SOP (11.43 mm (450))

#### **Quality Grade**

- A quality grade of the products is "Standard".
- Anti-radioactive design is not implemented in the products.
- Semiconductor devices have the possibility of unexpected defects by affection of cosmic ray that reach to the ground and so forth.



[MEMO]



# **Revision History**

Edition/	Pa	ge	Type of	Location	Description
Date	This Previous		revision		(Previous edition $ ightarrow$ This edition)
	edition	edition			
10th edition/	through	through	Modification	-	Ordering Information revised.
Nov. 2009					



#### NOTES FOR CMOS DEVICES -

#### 1) VOLTAGE APPLICATION WAVEFORM AT INPUT PIN

Waveform distortion due to input noise or a reflected wave may cause malfunction. If the input of the CMOS device stays in the area between  $V_{\rm IL}$  (MAX) and  $V_{\rm IH}$  (MIN) due to noise, etc., the device may malfunction. Take care to prevent chattering noise from entering the device when the input level is fixed, and also in the transition period when the input level passes through the area between  $V_{\rm IL}$  (MAX) and  $V_{\rm IH}$  (MIN).

#### ② HANDLING OF UNUSED INPUT PINS

Unconnected CMOS device inputs can be cause of malfunction. If an input pin is unconnected, it is possible that an internal input level may be generated due to noise, etc., causing malfunction. CMOS devices behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using pull-up or pull-down circuitry. Each unused pin should be connected to VDD or GND via a resistor if there is a possibility that it will be an output pin. All handling related to unused pins must be judged separately for each device and according to related specifications governing the device.

#### ③ PRECAUTION AGAINST ESD

A strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it when it has occurred. Environmental control must be adequate. When it is dry, a humidifier should be used. It is recommended to avoid using insulators that easily build up static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work benches and floors should be grounded. The operator should be grounded using a wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with mounted semiconductor devices.

#### **4) STATUS BEFORE INITIALIZATION**

Power-on does not necessarily define the initial status of a MOS device. Immediately after the power source is turned ON, devices with reset functions have not yet been initialized. Hence, power-on does not guarantee output pin levels, I/O settings or contents of registers. A device is not initialized until the reset signal is received. A reset operation must be executed immediately after power-on for devices with reset functions.

#### (5) POWER ON/OFF SEQUENCE

In the case of a device that uses different power supplies for the internal operation and external interface, as a rule, switch on the external power supply after switching on the internal power supply. When switching the power supply off, as a rule, switch off the external power supply and then the internal power supply. Use of the reverse power on/off sequences may result in the application of an overvoltage to the internal elements of the device, causing malfunction and degradation of internal elements due to the passage of an abnormal current.

The correct power on/off sequence must be judged separately for each device and according to related specifications governing the device.

#### 6 INPUT OF SIGNAL DURING POWER OFF STATE

Do not input signals or an I/O pull-up power supply while the device is not powered. The current injection that results from input of such a signal or I/O pull-up power supply may cause malfunction and the abnormal current that passes in the device at this time may cause degradation of internal elements. Input of signals during the power off state must be judged separately for each device and according to related specifications governing the device.

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